# RENESAS

# **USER'S MANUAL**

## ISL97687IRTZ-HEVALZ, ISL97687IRTZ-LEVALZ

### **Evaluation Board**

AN1674 Rev 0.00 October 12, 2011

The ISL97687 is a PWM controlled LED driver that supports 4 channels of LED current and LED peak current with jumpers for Monitor and TV LCD backlight applications. It is capable of driving 160mA per channel from a 9V to 32V input supply, with current sources rated up to 75V absolute maximum. ISL97687IRTZ has two types of driver boards:

"ISL97687IRTZ-LEVALZ" and "ISL97687IRTZ-HEVALZ" for driving up to 12 LEDs and 22 LEDs per channel, as shown in Figures 1, 2, 3, and 4. The key differences between each board are summarized in Table 1.

# **Quick Start Guide**

ISL97687 provides many different PWM dimming methods. The interface modes and its settings are summarized in Table 2. Those interfaces can be selected with switch and jumper settings of the evaluation board as shown in Figures 5 and 6.

Direct PWM Dimming Mode

Insert Jumper in the top position of the JP\_PWM\_SET to apply VDC to the PWM\_SET/PLL pin. In this mode, all other inputs (ACTL, STV, EN\_PS, EN\_VSYNC, EN\_ADIM) will be neglected. The LED dimming frequency and phase of the LEDs will be the same as the input of PWMI, as shown in Figures 7 and 8.

Decoded PWM Dimming Mode

Insert Jumper in the bottom position of the JP\_PWM\_SET to apply the POT resistor of R\_PWM\_SET to adjust LED dimming frequency in Figure 9. The JP\_CPLL should be opened.

#### VSYNC Mode

Connect the JP\_CPLL and disconnect the JP\_PWM\_SET. Set the switch SW\_EN\_VSYNC to be ON. The LED dimming frequency will be selected by frame signal coming to the STV pin (see the Table 1 in the <u>ISL97687</u> datasheet). Figure 11 shows the waveforms at VSYNC mode.

#### Phase Shift Mode

Connect Jumper to JP\_PWM\_SET for decoded PWM dimming mode or JP\_CPLL for VSYNC mode and then set switch SW\_EN\_PS to ON. Figure 10 shows phase shifted channel output. Figure 12 shows the channel output waveforms in the phase shifted VSYNC mode.

### ACTL Interface Mode

Connect Jumper JP\_PWM\_SET for decoded PWM dimming mode or JP\_CPLL for VSYNC mode and then set switch SW\_EN\_ADIM to ON. Apply an analog control signal of 0.3V (0% dimming) ~3.0V (100% dimming) with adjusting POT R\_ACTL or directly connect to the jumper pin by removing JP\_ACTL. In the ACTL or ACTL\*PWMI mode, the PWMI pin should not be floating or GND but tied to VDC or applying the PWM signal. The ISL97687 evaluation board provides the adjustments of boost switching frequency, LED dimming frequency, and LED peak current with jumpers and potentiometer,s as shown in Figure 6. Please use the following steps for the adjustment and selection of the analog settings.

#### Boost Switching Frequency Adjustment

Place jumper JP\_OSC to connect the OSC pin to the potentiometer and then change the resistance of the potentiometer R\_OSC for the boost switching frequency adjustment.

#### Dimming Frequency Adjustment

Place jumper JP\_PWM\_SET between the middle and lower pins to connect the PWM\_SET pin to the potentiometer for the dimming frequency adjustment.

#### LED Peak Current Adjustment

For two-step LED peak current settings, place jumper JP\_ISET1 and JP\_ISET2 each to connect potentiometers to the pin of ISET1 and ISET2. Adjust the LED peak current to change the resistance of the potentiometers, R\_ISET1 and R\_ISET2.

#### OVP Threshold Setting

The OVP level can be set based on Equation 1. The boost can regulate down to 30% of OVP. The OVP level should be considered max forward voltage of strings and margin of low temperature start-up.

 $\mathbf{OVP} = \mathbf{1.21V} \times (\mathbf{R}_{\mathbf{UPPER}} + \mathbf{R}_{\mathbf{LOWER}}) / \mathbf{R}_{\mathbf{LOWER}} \tag{EQ. 1}$ 

Please refer to the <u>ISL97687</u> datasheet for detailed switching and regulation adjustment.

For power-up, set switch SW\_nSHUT to high and connect JP\_nSHUT to PVIN. Apply input voltage to the PVIN and PGND pins based on the load conditions according to Table 1.

Each LED string can be configured with jumpers adjusted to a maximum of 12 LEDs for ISL97687IRTZ-LEVALZ or a maximum of 22 LEDs for ISL97687IRTZ-HEVALZ per channel. Please make sure the minimum number of LEDs/string will be limited by 30% of boost OVP level.

The populated LEDs are rated 150mA maximum, but care should be taken with the board temperature in setting the LED peak current according to the ambient temperature.

#### TABLE 1. COMPARISON OF ISL97687IRTZ-LEVALZ, ISL97687IRTZ-HEVALZ

| EVALUATION<br>BOARD    | ISL97687IRTZ-LEVALZ             | ISL97687IRTZ-HEVALZ             |
|------------------------|---------------------------------|---------------------------------|
| Max LEDs/Ch            | Driving up to 12 LEDs/Ch        | Driving up to 22 LEDs/Ch        |
| OVP Limit              | 49.6V (14.9V of 30% OVP)        | 79.3V (23.8V of 30% OVP)        |
| Current Limit          | 4.25A (sense resistor<br>40mΩ)  | 4.25A (sense resistor<br>40mΩ)  |
| Input Voltage<br>Range | 10V to 19V for<br>120mA/12 LEDs | 20V to 30V for<br>120mA/22 LEDs |



### ISL97687IRTZ-HEVALZ, ISL97687IRTZ-LEVALZ

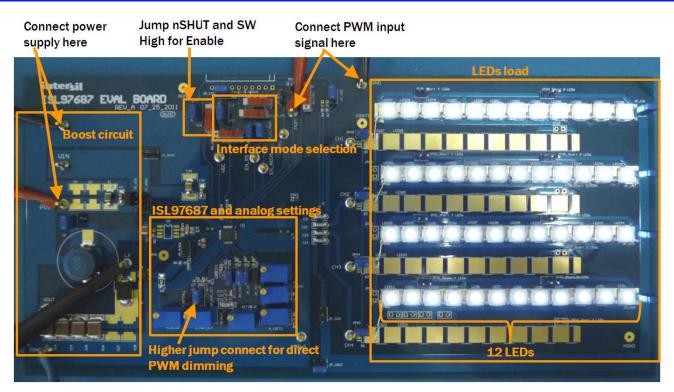


FIGURE 1. PHOTO OF ISL97687IRTZ-LEVALZ



FIGURE 2. PHOTO OF ISL97687IRTZ-HEVALZ





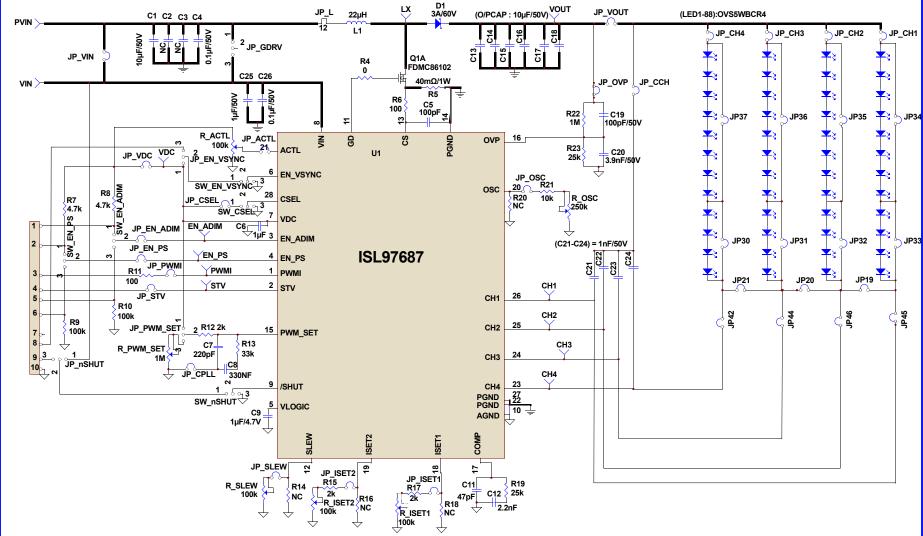


FIGURE 3. SCHEMATIC OF ISL97687IRTZ-LEVALZ

*ENESAS* 

ISL97687IRTZ-HEVALZ, ISL97687IRTZ-LEVALZ



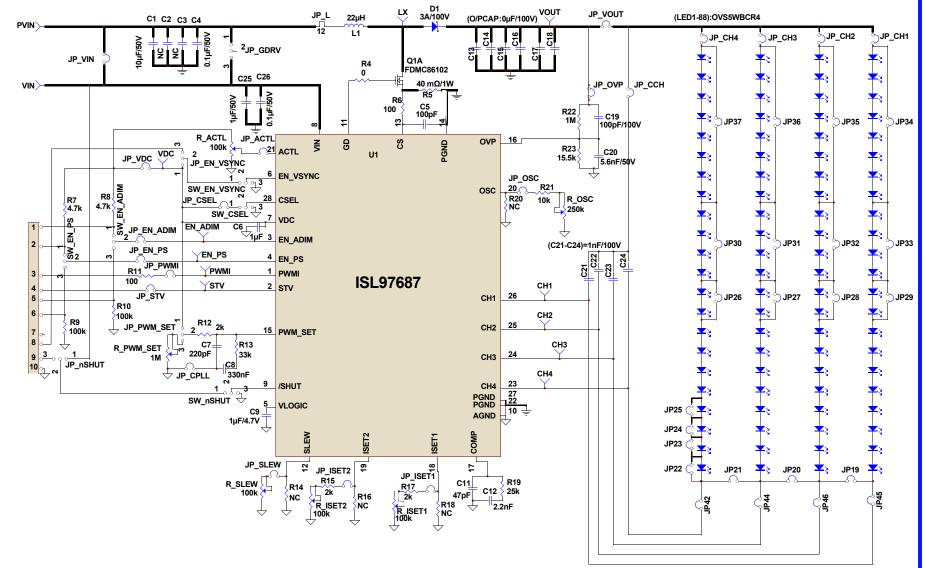


FIGURE 4. SCHEMATIC OF ISL97687IRTZ-HEVALZ

*ENESAS* 

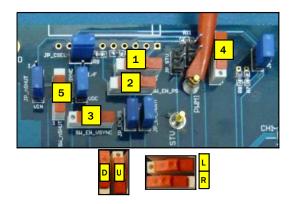
ISL97687IRTZ-HEVALZ, ISL97687IRTZ-LEVALZ

|                              | INPUT SIGNAL AND COMPONENT CONNECTION TO THE PIN                                       |      |      |     |         |          |       |
|------------------------------|--|------|------|-----|---------|----------|-------|
| INTERFACE MODE               | JP_PWM_SET/PLL   | PWMI | ACTL | STV | EN_ADIM | EN_VSYNC | EN_PS |
| Direct PWM dimming mode      | н  | Y    | Ν    | N   | N       | N        | Ν     |
| Direct PWM dimming mode only | Resistor connection for dimming<br>frequency adjustment                                | Y    | Ν    | Ν   | L       | L        | L     |
| VSYNC mode                   | RC loop filter for PLL   | Y    | Y    | Y   | Y       | Н        | Y     |
| Phase shift mode             | Resistor connection for dimming<br>frequency adjustment or RC loop<br>filter for VSYNC | Y    | Y    | Y   | Y       | Y        | Н     |
| ACTL mode                    | Resistor connection for dimming<br>frequency adjustment or RC loop<br>filter for VSYNC | Н    | Y    | Y   | н       | Y        | Y     |
| ACTL * PWMI mode             | Resistor connection for dimming<br>frequency adjustment or RC loop<br>filter for VSYNC | Y    | Y    | Y   | н       | Y        | Y     |

#### TABLE 2. SWITCH SETTINGS FOR INTERFACE MODE SELECTION

H: Tied to VDC Y: Input signal available or mode selectable

L: Tied to GND N: Input signal not available or negligible



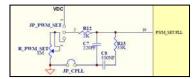
- 1 SW\_EN\_ADIM: Analog dimming mode, L:OFF, R:ON
- 2 SW\_EN\_PS: Phase shift mode, L: OFF, R: ON
- 3 SW\_EN\_VSYNC : Dim. synchronization with STV L:ON, R:OFF
- SW\_CSEL: LED current setting pin selection U: Select ISET2 pin D: Select ISET1 pin
- 5 SW\_nSHUT: ENABLE, D: OFF, U:ON

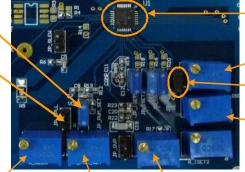
FIGURE 5. JUMP SETTINGS FOR INTERFACE MODE SELECTION

#### JP\_PWM\_SET

- HIGHER JUMP: Direct PWM dimming input mode - LOWER JUMP: Non direct PWM dimming (Dimming frequency setting by R\_PWM SET) mode

JP\_CPLL without jump JP\_PWM\_SET: VSYNC mode





- ISL97687

- Adjustment for ACTL input

Remove jumper to provide direct access to ACTL pin

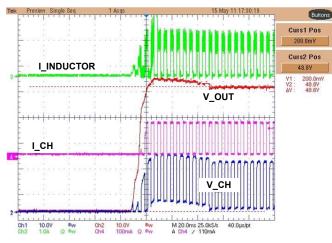
Adjustment for Boost frequency

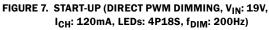
Adjustment for FPWM Adjustment for ISET1 Adjustment for ISET2

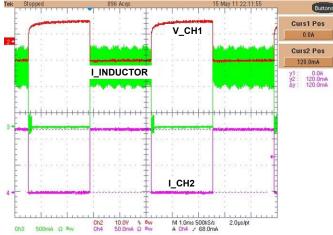
FIGURE 6. JUMP/RESISTOR SETTINGS FOR LED DIMMING CURRENT AND FREQUENCY ADJUSTMENT

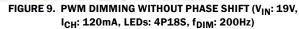


### ISL97687IRTZ-HEVALZ, ISL97687IRTZ-LEVALZ









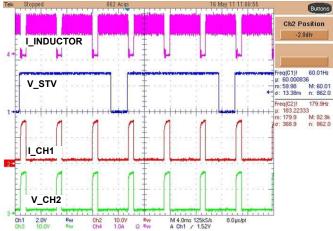


FIGURE 11. V<sub>SYNC</sub> ENABLED DIMMING WITHOUT PHASE SHIFT (V<sub>IN</sub>: 19V, I<sub>CH</sub>: 120mA, LEDs: 4P18S, 180Hz OUTPUT PHASE AND FREQUENCY LOCKED TO 60Hz STV)

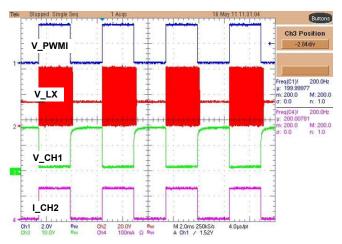


FIGURE 8. DIRECT PWM DIMMING (VIN: 19V, LEDs: 4P18S,  $f_{\text{DIM}}$ : 200Hz)

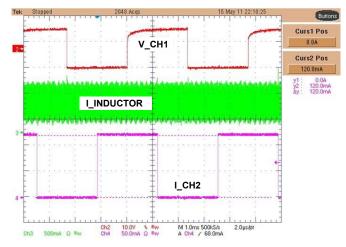
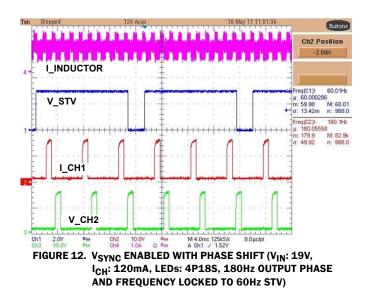


FIGURE 10. PWM DIMMING WITH PHASE SHIFT (V $_{\rm IN}$ : 19V, I $_{\rm CH}$ : 120mA, LEDs: 4P18S, f $_{\rm DIM}$ : 200Hz)





# ISL97687 Layout Guideline

Great care is needed in designing a PC board for stable ISL97687 operation. As shown in the typical application diagrams in Figures 3 and 4, the separation of PGND and AGND of each ISL97687 is essential, keeping the AGND referenced only local to the chip. This minimizes switching noise injection to the feedback sensing and analog areas, as well as eliminating DC errors from high current flow in resistive PC board traces. PGND and AGND should be on the top and bottom layers, respectively, in the two layer PCB in Figures 14 and 16. A star ground connection should be formed by connecting the LED ground return and AGND pins to the thermal pad with 9 to 12 vias shown in Figures 13 and 15. The ground connection should be into this ground net, on the top plane. The bottom plane then forms a quiet analog ground area, that both shields components on the top plane, as well as providing easy access to all sensitive components. For example, the ground side of the ISET1/2 resistors can be dropped to the bottom plane, providing a very low impedance path back to the AGND pin, which does not have any circulating high currents to interfere with it. The bottom plane can also be used as a thermal ground, so the AGND area should be sized sufficiently large to dissipate the required power. For multi-layer boards, the AGND plane can be the second layer. This provides easy access to the AGND net, but allows a larger thermal ground and main ground supply to come up through the thermal vias from a lower plane.

This type of layout is particularly important for this type of product, as the ISL97687 has a high power boost, resulting in high current flow in the main loop's traces. Careful attention should be focused on the following layout details:

- 1. Boost input capacitors, output capacitors, inductor and Schottky diode should be placed together in a nice tight layout. Keeping the grounds of the input, output, ISL97687 and the current sense resistor connected with a low impedance and wide metal is very important to keep these nodes closely coupled.
- 2. Figure 15 shows important traces of the current sensor (RS) and the OVP resistors (RU, RL). The current sensor track line should be short, so that it remains as close as possible to the Current Sense (CS) pin. Additionally, the CS pin is referenced from the adjacent PGND pin. It is extremely important that this PGND pin is placed with a good reference to the bottom of the sense resistor. In Figure 15, you can see that this ground pin is not connected to the thermal pad, but instead used to effectively sense the voltage at the bottom of the current sense resistor. However, this pin also takes the gate driver current, so it must still have a wide connection and a good connection back from the sense resistor to the star ground. Also, the RC filter on CS should be placed referenced to this PGND pin and be close to the chip.

- 3. If possible, try to maintain the central ground node on the board and use the input capacitors to avoid excessive input ripple for high output current supplies. The filtering capacitors should be placed close to the VIN pin.
- 4. For optimum load regulation and true  $V_{OUT}$  sensing, the OVP resistors should be connected independently to the top of the output capacitors and away from the higher dv/dt traces. The OVP connection then needs to be as short as possible to the pin. The AGND connection of the lower OVP components is critical for good regulation. At 70V output, a 100mV change at  $V_{OUT}$  translates to a 1.7mV change at OVP, so a small ground error due to high current flow, if referenced to PGND, can be disastrous.
- 5. The bypass capacitors connected to VDC and VLOGIC need to be as close to the pin as possible, and again, should be referenced to AGND. This is also true for the COMP network and the rest of the analog components (on ISET1/2, PWM\_SET, etc.).
- 6. The heat of the chip is mainly dissipated through the exposed thermal pad, so maximizing the copper area around it is a good idea. A solid ground is always helpful for the thermal and EMI performance.
- 7. The inductor and input and output capacitors should be mounted as tight as possible, to reduce the audible noise and inductive ringing.

### **General Power PAD Design Considerations**

Figure 13 shows an example of how to use vias to remove heat from the IC. We recommend you fill the thermal pad area with vias. A typical via array would be to fill the thermal pad footprint with vias spaced such that the center-to-center spacing is three times the radius of the via. Keep the vias small, but not so small that their inside diameter prevents solder wicking through the holes during reflow.

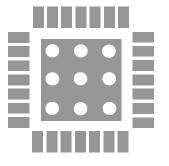


FIGURE 13. ISL97687 TQFN PCB VIA PATTERN



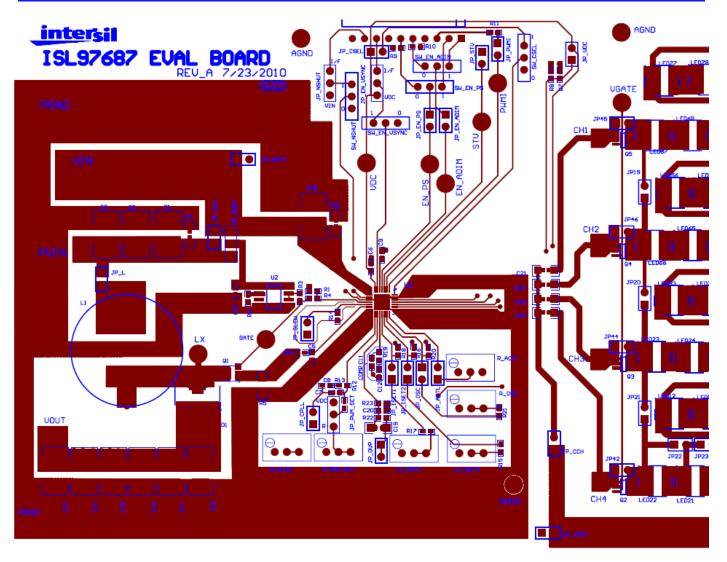


FIGURE 14. ISL97687 TOP LAYER OF EVALUATION BOARD

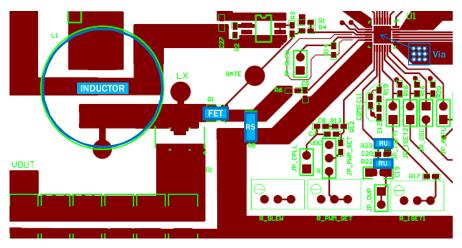


FIGURE 15. CURRENT SENSOR AND OVP RESISTORS



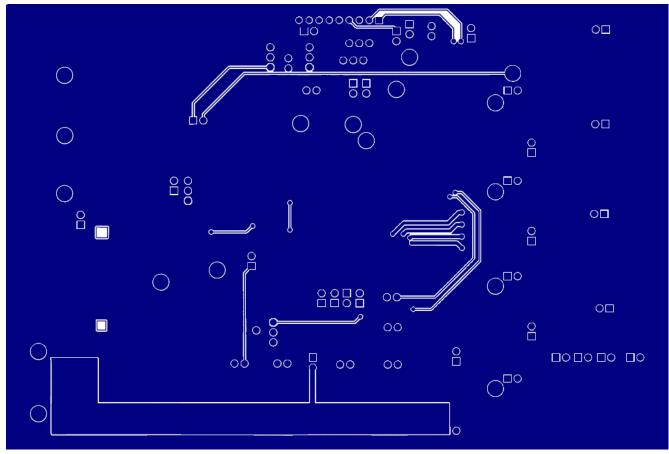


FIGURE 16. ISL97687 BOTTOM LAYER OF EVALUATION BOARD

# **Bill of Materials**

| ISL97687IRTZ-LEVALZ | ISL97687IRTZ-HEVALZ | DESIGNATOR         | FOOTPRINT   |
|---------------------|---------------------|--------------------|-------------|
| 0                   | 0                   | R4                 | 603         |
| 0                   | 0                   | R2                 | 603         |
| 0.1µF/50V           | 0.1µF/50V           | C26                | 805         |
| 0.1µF/50V           | 0.1µF/50V           | C4                 | 805         |
| 1M                  | 1M                  | R22                | 603         |
| 1nF/50V             | 1nF/100V            | C21, C22, C23, C23 | 805         |
| 1µF/10V             | 1µF/10V             | C6, C9             | 603         |
| 1µF/50V             | 1μF/50V             | C25                | 1210        |
| 2.2nF               | 2.2nF               | C12                | 603         |
| 2k                  | 2k                  | R12, R15, R17      | 603         |
| 3A/60V              | 3A/100V             | D1                 | SMB/C/D2PAK |
| 4.7k                | 4.7k                | R7, R8             | 603         |
| 4.7µF/50V           | 4.7µF/50V           | C27                | 603         |
| 3.9nF               | 5.6nF               | C20                | 603         |
| 100                 | 100                 | R6, R11            | 603         |
| 100k                | 100k                | R9, R10            | 603         |



| <b>Bill of Ma</b> | aterials | (Continued) |
|-------------------|----------|-------------|
|-------------------|----------|-------------|

| ISL97687IRTZ-LEVALZ                   | ISL97687IRTZ-HEVALZ                     | DESIGNATOR              | FOOTPRINT            |
|---------------------------------------|---|-------------------------|----------------------|
| 100k                                  | 00k 100k R_SLEW                         |                         | VRES                 |
| 100k                                  | 100k                                    | R_ISET2                 | VRES                 |
| 100k                                  | 100k                                    | R_ISET1                 | VRES                 |
| 100k                                  | 100k                                    | R_ACTL                  | VRES                 |
| 1M                                    | 1M                                      | R_PWM_SET               | VRES                 |
| 250k                                  | 250k                                    | R_OSC                   | VRES                 |
| 100pF                                 | 100pF                                   | C5                      | 603                  |
| 100pF/50V                             | 100pF/100V                              | C19                     | C19                  |
| 10k                                   | 10k                                     | R21                     | 603                  |
| 10µF/50V                              | 10µF/100V                               | C13, C14, C15, C16, C17 | 1210/2220            |
| 10µF/35V                              | 10µF/35V                                | C1                      | 1210                 |
| 22µH                                  | 22µH                                    | L1                      | SLF12575T-220M4R0-PF |
| 25k use for V <sub>OUT</sub> OVP: 50V | 15.5k use for V <sub>OUT</sub> OVP: 80V | R23                     | 603                  |
| 25k use for V <sub>OUT</sub> OVP: 50V | 25k use for V <sub>OUT</sub> OVP: 50V   |                         |                      |
| 40mΩ/1W                               | 40mΩ/1W                                 | R5                      | 1206                 |
| 220pF                                 | 220pF                                   | C7                      | 603                  |
| 25k                                   | 25k                                     | R19                     | 603                  |
| 330nF                                 | 330nF                                   | C8                      | 603                  |
| 33k                                   | 33k                                     | R13                     | 603                  |
| 47pF                                  | 47pF                                    | C11                     | 603                  |
| FDMC86102                             | FDMC86102                               | Q1                      | FDMC86102            |
| SWITCH                                | SWITCH                                  | SW_EN_PS                | SWITCH-SLIDE-SPDT    |
| SWITCH                                | SWITCH                                  | SW_CSEL                 | SWITCH-SLIDE-SPDT    |
| SWITCH                                | SWITCH                                  | SW_EN_ADIM              | SWITCH-SLIDE-SPDT    |
| SWITCH                                | SWITCH                                  | SW_EN_VSYNC             | SWITCH-SLIDE-SPDT    |
| 150mA/3.2V                            | 150mA/3.2V                              | (LED1:LED88)            | OVS5WBCR4            |



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